

NCE N-Channel Super Trench II Power MOSFET

Description

The series of devices uses Super Trench II technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{\text{DS}(\text{ON})}$ and $Q_{\text{g}}.$ This device is ideal for high-frequency switching and synchronous rectification.

Application

- DC/DC Converter
- ●Ideal for high-frequency switching and synchronous rectification

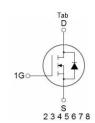
General Features

- V_{DS} =200V,I_D =125A $R_{\text{DS(ON)}}\text{=}7.4\text{m}\Omega$, typical @ $V_{\text{GS}}\text{=}10V$
- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% AVds TESTED!

TOLL-8L





Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP090N20LL	NCEP090N20LL	TOLL-8L	-	-	-

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	200	V
Gate-Source Voltage	V _{GS}	±20	V
Drain Current-Continuous	I _D	125	А
Drain Current-Continuous(T _C =100 °C)	I _D (100℃)	88	А
Pulsed Drain Current	I _{DM}	500	А
Maximum Power Dissipation	P _D	490	W
Derating factor		3.27	W/°C
Single pulse avalanche energy (Note 1)	Eas	2079	mJ
Operating Junction and Storage Temperature Range	T_{J}, T_{STG}	-55 To 175	$^{\circ}$

Thermal Characteristic

hermal Resistance,Junction-to-Case	Rejc	0.31	°C/W
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Electrical Characteristics (T_C=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	200	-	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =200V,V _{GS} =0V	-	-	1	μΑ
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	2.0	3.3	4.0	V
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =20A	-	7.4	9.0	mΩ
Forward Transconductance	G FS	V _{DS} =15V,I _D =20A	-	70	-	S
Dynamic Characteristics						
Input Capacitance	C _{lss}	\/ 400\/\/ 0\/	-	6000	-	pF
Output Capacitance	Coss	V_{DS} =100V, V_{GS} =0V,	-	535	-	pF
Reverse Transfer Capacitance	C _{rss}	F=1.0MHz	-	17.5	-	pF
Switching Characteristics (Note 2)						
Turn-on Delay Time	t _{d(on)}		-	54	-	nS
Turn-on Rise Time	t _r	V_{DD} =100 V , I_D =20 A	-	38	-	nS
Turn-Off Delay Time	t _{d(off)}	V_{GS} =10 V , R_{G} =4.7 Ω	-	65	-	nS
Turn-Off Fall Time	t _f		-	15	-	nS
Total Gate Charge	Qg	V 400V/I 00A	-	95	-	nC
Gate-Source Charge	Q _{gs}	V _{DS} =100V,I _D =20A, V _{GS} =10V	-	30.5	-	nC
Gate-Drain Charge	Q _{gd}		-	24.5	-	nC
Drain-Source Diode Characteristics	·					
Diode Forward Voltage	V _{SD}	V _{GS} =0V,I _S =20A	-	-	1.2	V
Diode Forward Current	Is		-	-	125	Α
Reverse Recovery Time	t _{rr}	T _J = 25°C, I _F = 50A	-	98	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs	-	260	-	nC

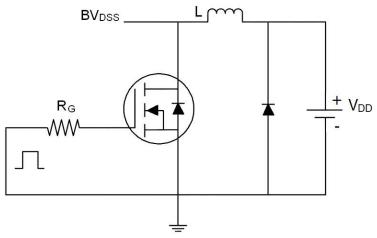
Notes:

- 1. EAS condition : Tj=25 $^{\circ}\text{C}$,V_DD=50V,V_G=10V,L=0.5mH,Rg=25 Ω
- 2. Guaranteed by design, not subject to production
- 3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heat sink, assuming a maximum junction temperature of TJ(MAX)=175°C. The SOA curve provides a single pulse rating.

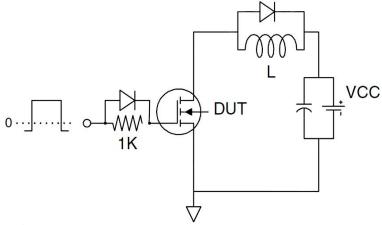


Test Circuit

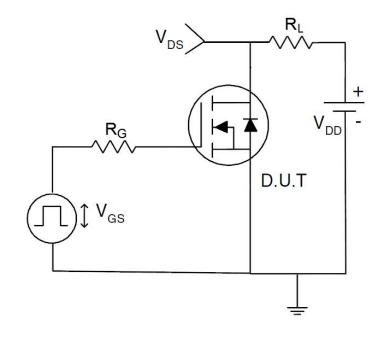
1) E_{AS} test Circuit



2) Gate charge test Circuit



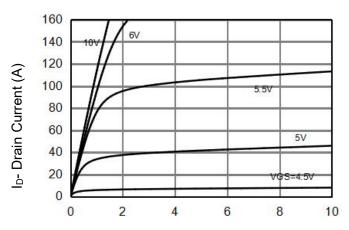
3) Switch Time Test Circuit





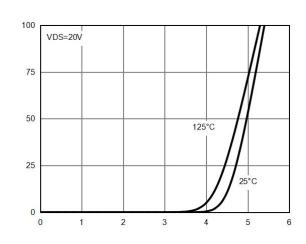
D- Drain Current (A)

Typical Electrical and Thermal Characteristics



Vds Drain-Source Voltage (V)





Vgs Gate-Source Voltage (V)
Figure 2 Transfer Characteristics

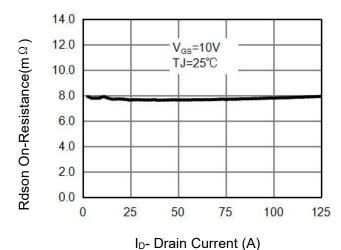


Figure 3 Rdson- Drain Current

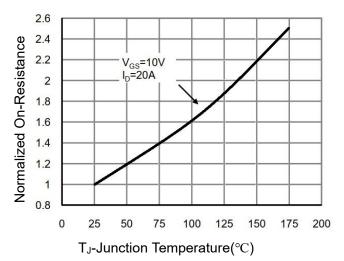


Figure 4 Rdson-JunctionTemperature

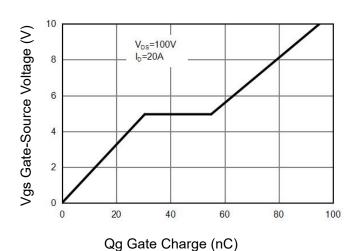


Figure 5 Gate Charge

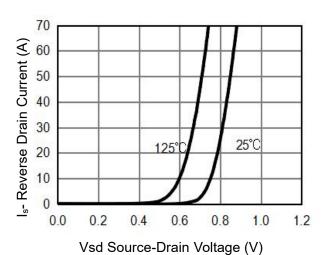
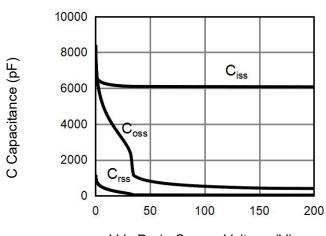


Figure 6 Source- Drain Diode Forward





Vds Drain-Source Voltage (V)
Figure 7 Capacitance vs Vds

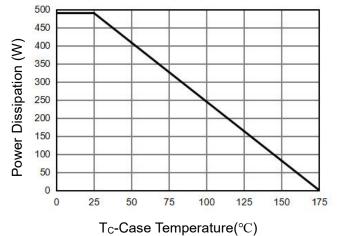


Figure 9 Power De-rating

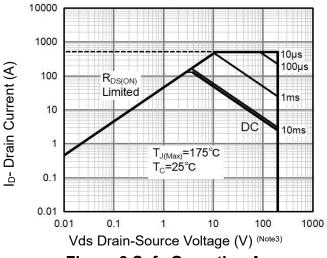


Figure 8 Safe Operation Area

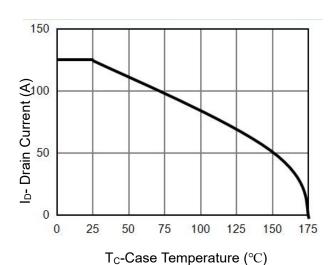


Figure 10 Current De-ratin

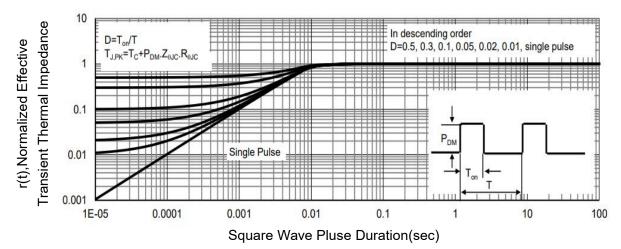
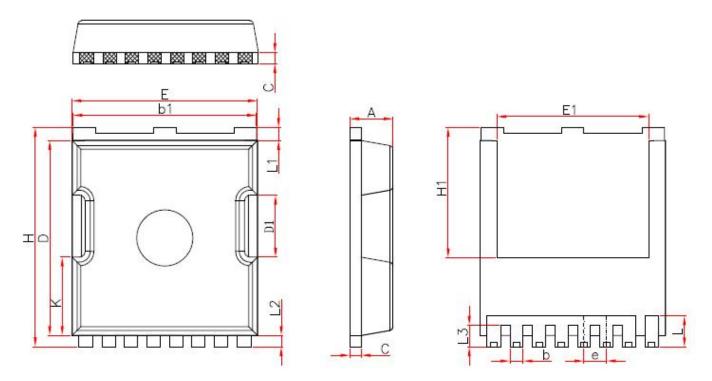


Figure 11 Normalized Maximum Transient Thermal Impedance



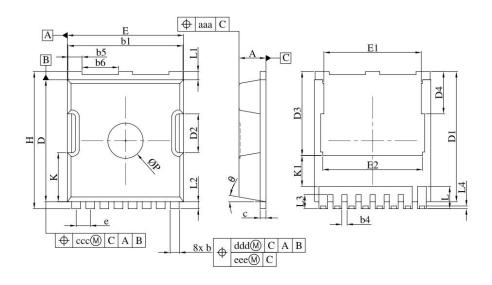
TOLL(E) Package Information

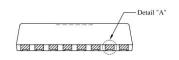


Symbol	Millimeters			
Vice	Min.	Nom.	Max.	
A	2. 20	2.30	2.40	
b	0.65	0.75	0.85	
b1	9.70	9.80	9.90	
C	0.50	0.60	0.70	
D	10.30	10.40	10.50	
D1	3.15	3.3	3.45	
Е	9.70	9.90	10.10	
E1	8.00	8.10	8.20	
е	1.10	1.20	1.30	
Н	11.6	11.7	11.8	
H1	6.85	6.95	7.05	
K	4.08	4.18	4. 28	
L	1.60	1.65	2.10	
L1	0.60	0.70	0.80	
L2	0.50	0.60	0.70	
L3	1.05	1.20	1.30	



TOLL(J) Package Information







S	COMMON						
M B O	MILLIMETER						
L L	MIN.	NOMINAL	MAX.				
A	2.20	2.30	2.40				
b	0.70	0.80	0.90				
bl	9.70	9.80	9.90				
b2	0.36	0.45	0.55				
b3	0.05	0.100	0.35				
b4	0.30	0.40	0.50				
b5	1.10	1.20	1.30				
b6	3.00	3.10	3.20				
С	0.40	0.50	0.60				
D	10.28	10.38	10.55				
Dl	10.98	11.08	11.18				
D2	3.20	3.30	3.40				
D3	7.00	7.15	7.30				
D4	3.44	3.59	3.74				
e	1.10	1.20	1.30				
E	9.80	9.90	10.00				
El	8.20	8.30	8.40				
E2	8.35	8.50	8.65				
Н	11.50	11.68	11.85				
K	4.08	4.18	4.28				
K1	2.45						
L	1.60	1.90	2.10				
Ll	0.50	0.70	0.90				
L2	0.50	0.60	0.70				
L3	1.00	1.20	1.30				
L4	0.13	0.23	0.33				
P	2.85	3.00	3.15				
θ	10° REF						
aaa	0.20						
ccc	0.20						
ddd	0.25						
eee	0.20						



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